Power MOSFET

30 V, 3.2 A, Single N-Channel, SC-88

Features

- Offers an Low R_{DS(on)} Solution in the SC-88 Package
- Low Profile (< 1.1 mm) Allows it to fit Easily into Extremely Thin Environments such as Portable Electronics
- Operates at Standard Logic Level Gate Drive
- Low Gate Charge
- This is a Pb-Free Device

Applications

- DC-DC Converters (Buck and Boost Circuit)
- Optimized for Battery Powered Portable Equipment such as, Cell Phones, PDAs, Media Players, etc.
- Load Management
- Battery Charging and OV IC Protection Circuits

MAXIMUM RATINGS (T_J = 25° C unless otherwise stated)

Param	Symbol	Value	Unit		
Drain-to-Source Voltage	V _{DSS}	30	V		
Gate-to-Source Voltage	V _{GS}	±20	V		
Continuous Drain	Steady	T _A = 25 °C	۱ _D	2.6	А
Current (Note 1)	State	T _A = 85 °C		1.9	
	t ≤ 1 s	T _A = 25 °C		3.2	
Power Dissipation (Note 1)	Steady State T _A = 25 °C		P _D	0.62	W
	t ≤ 1 s			0.95	
Continuous Drain	Steady	T _A = 25 °C	Ι _D	1.8	А
Current (Note 2)		T _A = 85 °C		1.3	
Power Dissipation (Note 2)	State	T _A = 25 °C	PD	0.3	W
Pulsed Drain Current	t _p =	= 10 μs	I _{DM}	10	А
Operating Junction and Storage Temperature			T _J , T _{STG}	-55 to 150	°C
Source Current (Body Diode)			۱ _S	1.3	А
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).

2. Surface mounted on FR4 board using the minimum recommended pad size.



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V _{(BR)DSS}	R _{DS(on)} TYP	I _D Max
30 V -	45 m Ω @ 10 V	3.2 A
	65 mΩ @ 4.5 V	5.2 A



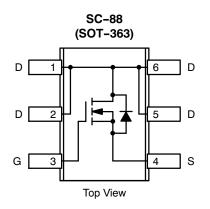




T7 = Device Code

M = Date Code

- = Pb-Free Package
- (Note: Microdot may be in either location)



ORDERING INFORMATION

Device	Package	Shipping [†]
NTJS4160NT1G	SC-88 (Pb-Free)	3000 Units/Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

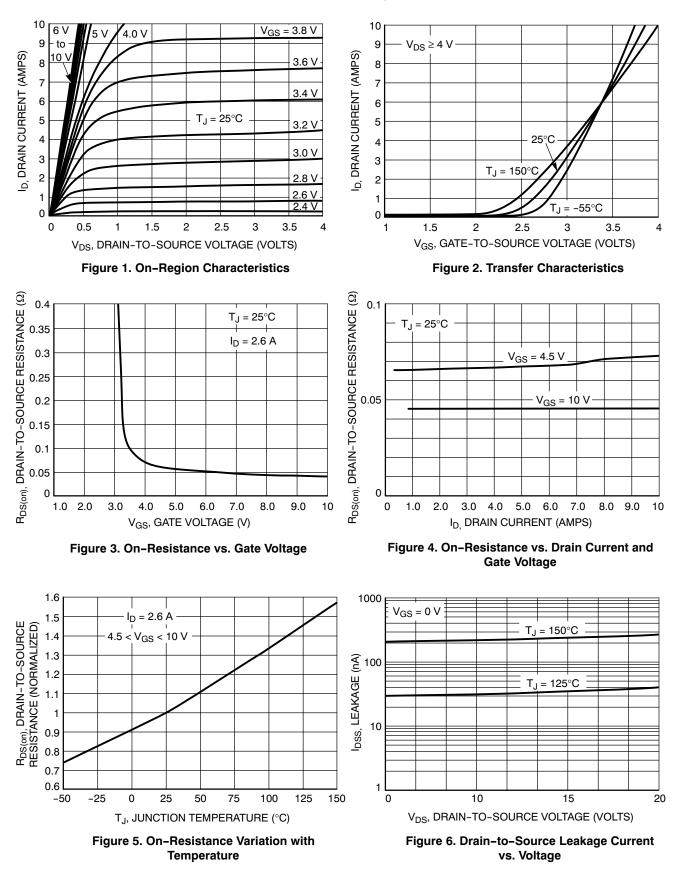
Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	200	°C/W
Junction-to-Ambient – t \leq 1 s (Note 3)	$R_{ hetaJA}$	132	
Junction-to-Ambient - Steady State (Note 4)	$R_{ hetaJA}$	420	

Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
Surface mounted on FR4 board using the minimum recommended pad size.

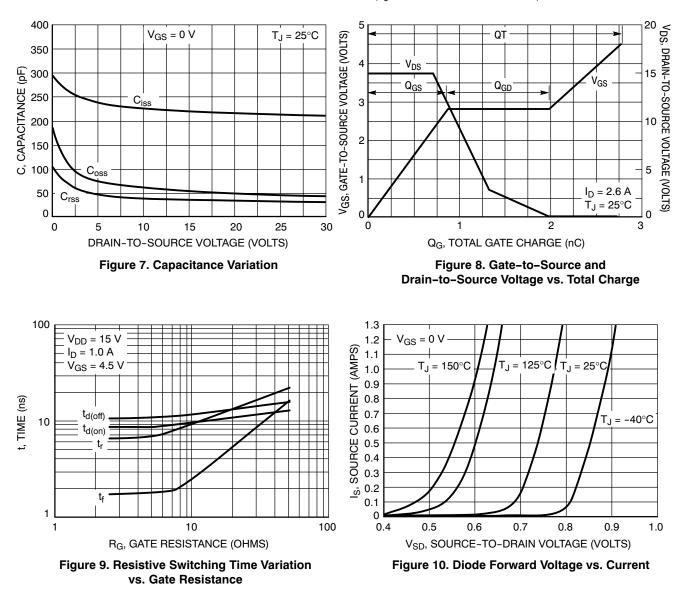
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Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•					•	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 250 μA		30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = 250 μA, ref to 25°C			20		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$ $T_J = 25^{\circ}C$ $V_{DS} = 24 V$ $T_J = 125^{\circ}C$				1.0 10	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = +20 V$				100	nA
		V _{DS} = 0 V, V _{GS} =	= -20 V			-200	1
ON CHARACTERISTICS (Note 5)						•	
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D =$	250 μΑ	0.8		2.4	V
Gate Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 2.6 A V_{GS} = 4.5 V, I _D = 2.2 A			45	60	mΩ
					65	85	1
Forward Transconductance	9 FS	$V_{GS} = 5.0 \text{ V}, \text{ I}_{D} = 3.0 \text{ A}$			4.2		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}				230		pF
Output Capacitance	C _{OSS}	V _{GS} = 0 V, f = 1. V _{DS} = 10	V _{GS} = 0 V, f = 1.0 MHz, V _{DC} = 10 V		62		
Reverse Transfer Capacitance	C _{RSS}				39		
Total Gate Charge	Q _{G(TOT)}				2.75		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS}	= 15 V,		0.37		
Gate-to-Source Charge	Q _{GS}	$I_{\rm D} = 2.6$ Å	A		0.87		
Gate-to-Drain Charge	Q _{GD}				1.1		
SWITCHING CHARACTERISTICS (Note	6)	·			-		-
Turn-On Delay Time	t _{d(ON)}				8.7	15	ns
Rise Time	t _r	V _{GS} = 4.5 V, V _{DD}	= 15 V,		7.2	13	
Turn-Off Delay Time	t _{d(OFF)}	$I_{\rm D} = 1.0 \text{ A}, \text{ R}_{\rm G} =$	= 6.0 Ώ		10.9	19	
Fall Time	t _f	1 1			1.9	4.0	7
DRAIN-SOURCE DIODE CHARACTERI	STICS	·	-		-		-
Forward Diode Voltage	V _{SD}		$\Gamma_{\rm J} = 25^{\circ}\rm C$		0.79	1.2	V
	+		_J = 125°C		0.67		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 1.3 A			10.3	ļ	ns
Charge Time	T _a				7.2		
Discharge Time	Tb				3.1		nC
Reverse Recovery Charge	Q _{RR}				4.0		

5. Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
6. Switching characteristics are independent of operating junction temperatures.



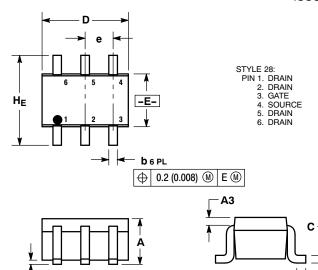
TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)



TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)

PACKAGE DIMENSIONS

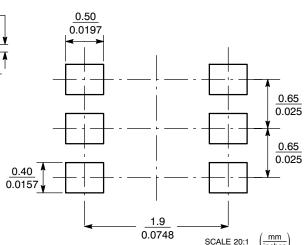
SC-88 (SOT-363) CASE 419B-02 ISSUE W



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 2.
- 419B-01 OBSOLETE, NEW STANDARD 419B-02. 3.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.95	1.10	0.031	0.037	0.043	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	0.20 REF			0.008 REF			
b	0.10	0.21	0.30	0.004	0.008	0.012	
С	0.10	0.14	0.25	0.004	0.005	0.010	
D	1.80	2.00	2.20	0.070	0.078	0.086	
Е	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0	.026 BS	С	
Г	0.10	0.20	0.30	0.004	0.008	0.012	
HE	2.00	2.10	2.20	0.078	0.082	0.086	



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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